3SK 169

Silicon N Channel 4-pole MOS Type

For VHF high-gain low-noise amplification mixers

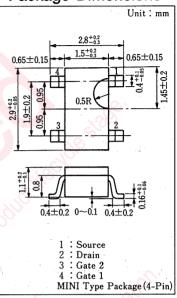
■ Features

- •Large power gain PG
- •A MINI type package that allows downsizing of equipment and automatic insertion by taping and magazine packaging

■ Absolute Maximum Ratings (Ta=25°C)

Item	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	15	V
Gate 1-Source Voltage	V _{G1S}	±8	v
Gate 2-Source Voltage	V_{G2S}	±8	-V
Drain Current	I_D	30	mA
Power Dissipation	P _D	150	mW
Channel Temperature	T _{ch}	150	° 0
Storage Temperature	T _{stg}	-55~+150	C

■ Package Dimensions



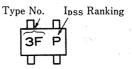
■ Electrical Characteristics (Ta=25°C)

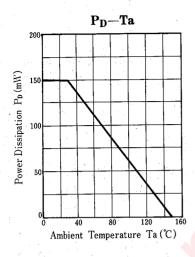
Item	Symbol	Condition	min.	typ.	max:	Unit
Drain Current	I _{DSS} *	$V_{DS} = 10V$, $V_{G1S} = 0$, $V_{G2S} = 4V$	1.5		10	mA
Gate 1 Cutoff Current	I _{G1SS}	$V_{DS} = 0$, $V_{G2S} = 0$, $V_{G1S} = \pm 8 V$	90	30,	±20	n A
Gate 2 Cutoff Current	I _{G2SS}	$V_{DS} = 0$, $V_{G1S} = 0$, $V_{G2S} = \pm 8 V$, S	O	±20	, nA
Drain-Source Voltage	V_{DSK}	$I_D = 50 \mu\text{A}, \ V_{G1S} = -5 \text{V}, \ V_{G2S} = 0$	15			V
Gate 1-Source Cutoff Current	V_{G1S1}	$V_{DS} = 10V$, $V_{G2S} = 4V$, $I_{D} = 100 \mu A$	-3		+0.5	V
Gate 2-Source Cutoff Current	V _{G2S1}	$V_{DS} = 10V$, $V_{G1S} = 0$, $I_{P} = 100 \mu\text{A}$	-2		+0.5	V
Forward Transfer Admittance (Common Source)	Y _{fs}	$V_{DS}=10V$, $I_{D}=10mA$, $V_{G2S}=4V$, $f=1 \text{ kHz}$	23	30		mS
Input Capacitance	C _{iss}	V -10V V 5		4.5	5.7	pF
Output Capacitance	Coss	$V_{DS} = 10V$, $V_{G1S} = -5V$, $V_{G2S} = -5V$, $f = 1MHz$		1.7	2.2	pF
Small-Signal Reverse Transfer Capacitance	C_{rss}	es moil		0.02		pF
Gain Reduction	CG	$V_{DS} = 8 \text{ V}, V_{G2S} = 3 \text{ V}, I_D = 1 \text{ mA},$ $f = 200 \text{MHz}, f_{LO} = 245 \text{MHz}, P_{LO} = 10 \text{dBm}$	13	17		dB

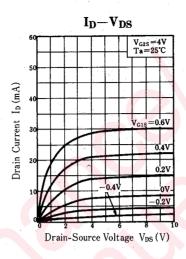
*IDSS Ranking

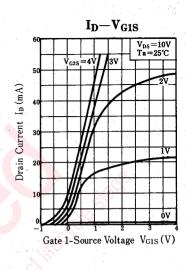
Rank	Р	Q
I _{DSS} (mA)	1.5~5	3~10
Marking	3FP	3FQ

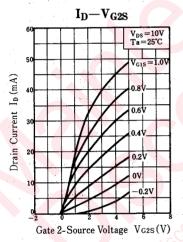
■ Type Name Marking (Example)

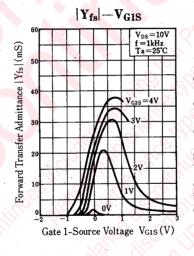


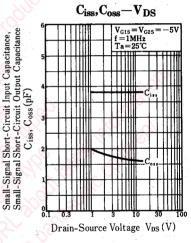


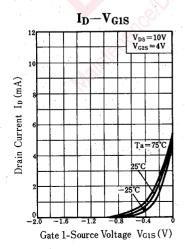












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